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CONFIRMATION NO. 6747

<b>SERIAL NUMBER</b> 10/511,712	<b>FILING OR 371(c) DATE</b> 04/18/2005 <b>RULE</b>	<b>CLASS</b> 365	<b>GROUP ART UNIT</b> 2827	<b>ATTORNEY DOCKET NO.</b> 03GR029(54517)
<b>APPLICANTS</b> Philippe Gendrier, Grenoble, FRANCE; Cyrille Dray, Eybens, FRANCE; Richard Fournel, Lumbin, FRANCE; Sebastien Poirier, Vizille, FRANCE; Daniel Caspar, Saint Hilaire du Touvet, FRANCE; Philippe Candelier, Saint Mury Monteymond, FRANCE;				
<b>** CONTINUING DATA *****</b> This application is a 371 of PCT/FR03/00311 01/31/2003 <i>yes, TL</i>				
<b>** FOREIGN APPLICATIONS *****</b> FRANCE 0204690 04/15/2002 <i>yes, TL</i> FRANCE 0209454 07/25/2002				
Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no 35 USC 119 (a-d) conditions <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after met Verified and <i>TL</i> Acknowledged Examiner's Signature _____ Initials _____		<b>STATE OR COUNTRY</b> FRANCE	<b>SHEETS DRAWING</b> 15	<b>TOTAL CLAIMS</b> 67
				<b>INDEPENDENT CLAIMS</b> 2
<b>ADDRESS</b> 27975				
<b>TITLE</b> Electrically erasable and programmable, non-volatile semiconductor memory device having a single layer of gate material, and corresponding memory plane				
<b>FILING FEE RECEIVED</b> 1926	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following:		<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees ( Filing ) <input type="checkbox"/> 1.17 Fees ( Processing Ext. of time ) <input type="checkbox"/> 1.18 Fees ( Issue ) <input type="checkbox"/> Other _____ <input type="checkbox"/> Credit	